

# FK8V03050L

## Silicon N-channel MOSFET

For lithium-ion secondary battery protection circuit  
 For DC-DC Converter

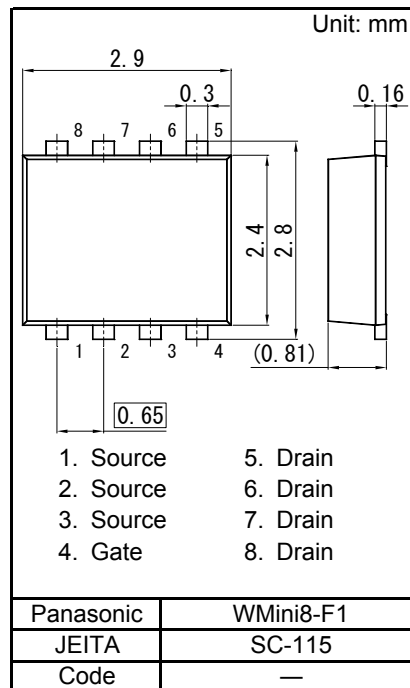
■ Features

- Low drain-source On-state Resistance  
 RDS(on) typ = 16 mΩ (VGS = 4.5 V)
- High-speed switching : Qg = 5.1 nC
- Halogen-free / RoHS compliant  
 (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)

■ Marking Symbol: 3E

■ Packaging

Embossed type (Thermo-compression sealing) : 3 000 pcs / reel (standard)



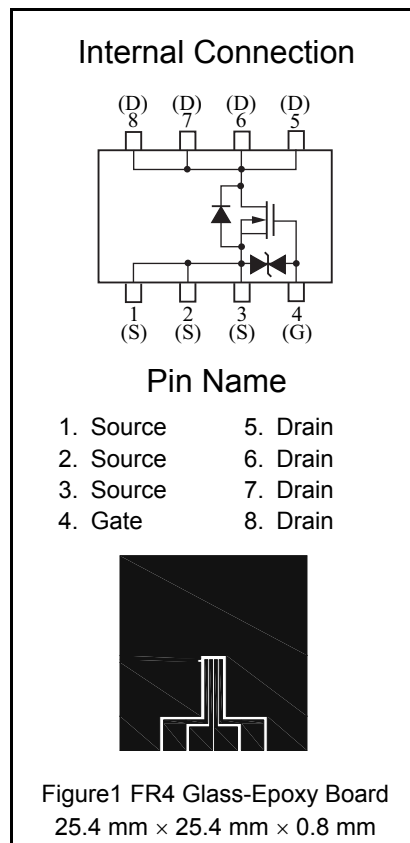
- |           |          |
|-----------|----------|
| 1. Source | 5. Drain |
| 2. Source | 6. Drain |
| 3. Source | 7. Drain |
| 4. Gate   | 8. Drain |

■ Absolute Maximum Ratings Ta = 25 °C

| Parameter                                     | Symbol      | Rating      | Unit |
|---|-------------|-------------|------|
| Drain-source Voltage                          | VDS         | 33          | V    |
| Gate-source Voltage                           | VGS         | ±20         | V    |
| Drain Current (Steady State) *1               | ID          | 8           | A    |
| Drain Current (t = 10 s) *1                   |             | 10          |      |
| Drain Current (Pulsed) *1,*2                  |             | 32          |      |
| Source Current (Pulsed)<br>(Body Diode) *1,*2 | ISp<br>(BD) | 8           |      |
| Total Power Dissipation (Steady State) *1     | PD          | 1           | W    |
| Total Power Dissipation (t = 10 s) *1         |             | 1.5         |      |
| Channel Temperature                           | Tch         | 150         | °C   |
| Operating Ambient Temperature                 | Topr        | -40 to +85  | °C   |
| Storage Temperature Range                     | Tstg        | -55 to +150 | °C   |

Note) \*1 Device mounted on a glass-epoxy board (See Figure 1)

\*2 Pulse test: Ensure that the channel temperature does not exceed 150°C



■ Electrical Characteristics Ta = 25°C ± 3°C

Static Characteristics

| Parameter                           | Symbol   | Conditions               | Min | Typ | Max | Unit |
|-------------------------------------|----------|--------------------------|-----|-----|-----|------|
| Drain-source Breakdown Voltage      | VDSS     | ID = 1 mA, VGS = 0 V     | 33  |     |     | V    |
| Zero Gate Voltage Drain Current     | IDSS     | VDS = 33 V, VGS = 0 V    |     |     | 10  | μA   |
| Gate-source Leakage Current         | IGSS     | VGS = ±16 V, VDS = 0 V   |     |     | ±10 | μA   |
| Gate-source Threshold Voltage       | Vth      | ID = 0.73 mA, VDS = 10 V | 1   |     | 2.5 | V    |
| Drain-source On-state Resistance *1 | RDS(on)1 | ID = 4A, VGS = 10 V      |     | 11  | 15  | mΩ   |
|                                     | RDS(on)2 | ID = 4A, VGS = 4.5 V     |     | 16  | 25  |      |

Dynamic Characteristics

| Parameter                    | Symbol  | Conditions                                | Min | Typ | Max | Unit |
|------------------------------|---------|---|-----|-----|-----|------|
| Input Capacitance            | Ciss    | VDS = 10 V, VGS = 0 V,<br>f = 1 MHz       |     | 520 |     | pF   |
| Output Capacitance           | Coss    |   |     | 110 |     |      |
| Reverse Transfer Capacitance | Crss    |   |     | 70  |     |      |
| Turn-on Delay Time *2        | td(on)  | VDD = 15 V, VGS = 0 to 10 V               |     | 8   |     | ns   |
| Rise Time *2                 | tr      | ID = 4 A                                  |     | 4   |     |      |
| Turn-off Delay Time *2       | td(off) | VDD = 15 V, VGS = 10 to 0 V               |     | 32  |     |      |
| Fall Time *2                 | tf      | ID = 4 A                                  |     | 10  |     |      |
| Total Gate Charge            | Qg      | VDD = 15 V, VGS = 0 to 4.5 V,<br>ID = 8 A |     | 5.1 |     | nC   |
| Gate-source Charge           | Qgs     |   |     | 1.8 |     |      |
| Gate-drain Charge            | Qgd     |   |     | 2.3 |     |      |

Body Diode Characteristic

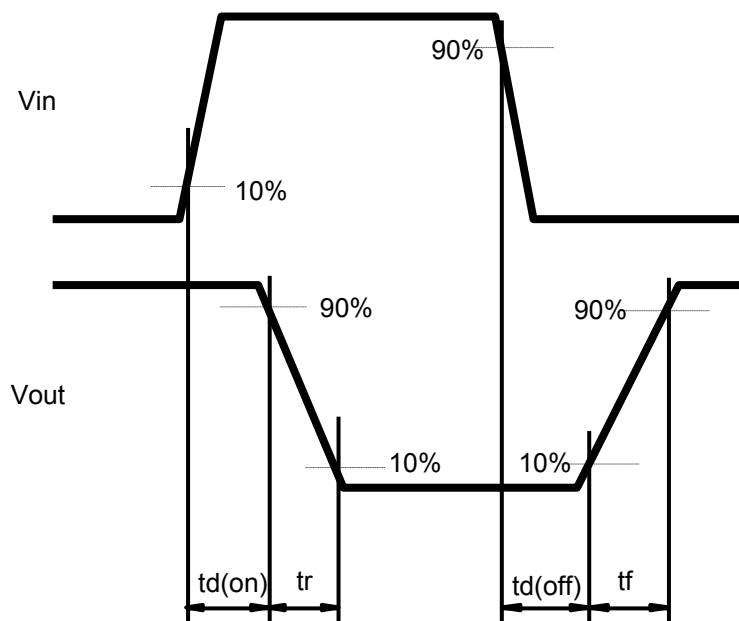
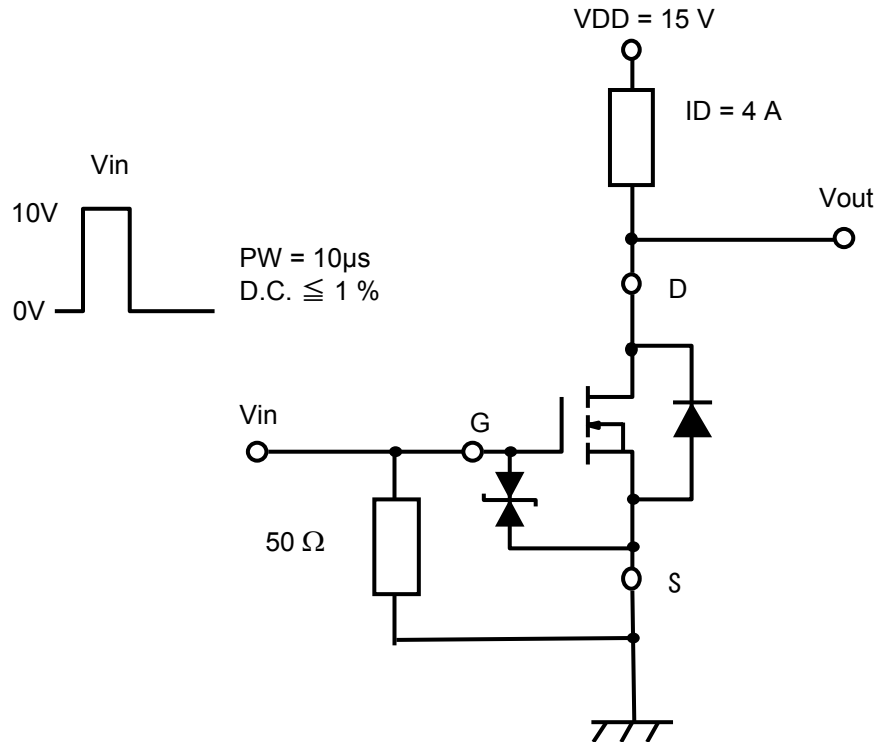
| Diode Forward Voltage *1 | VSD | IS = 4 A, VGS = 0 V | Min | Typ | Max | Unit |
|--------------------------|-----|---------------------|-----|-----|-----|------|
|                          |     |                     |     | 0.8 | 1.2 | V    |

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

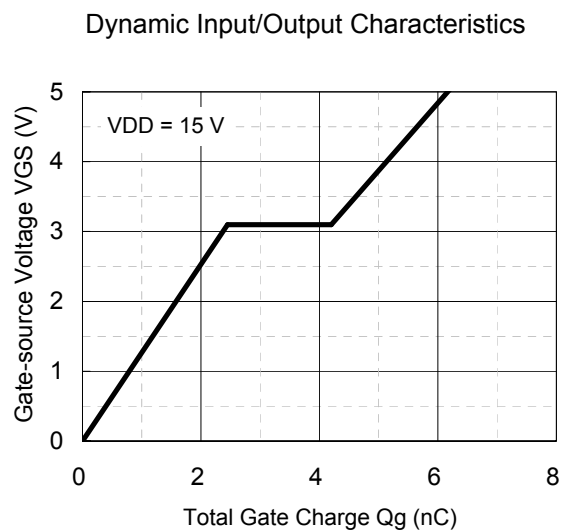
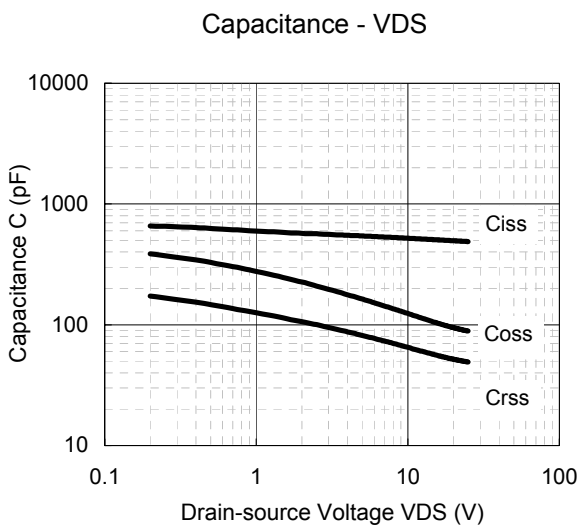
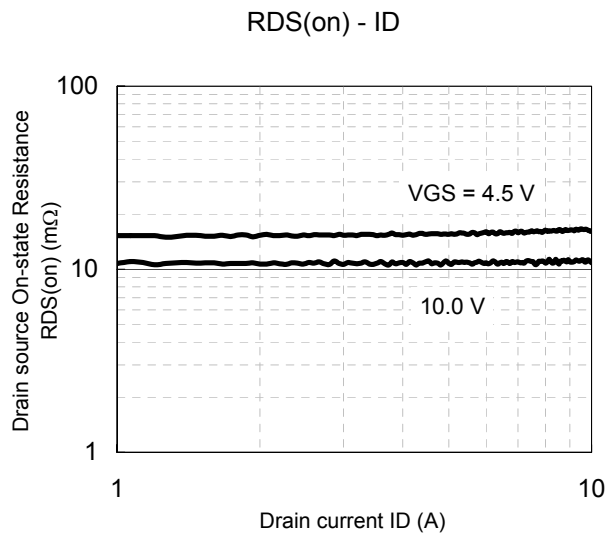
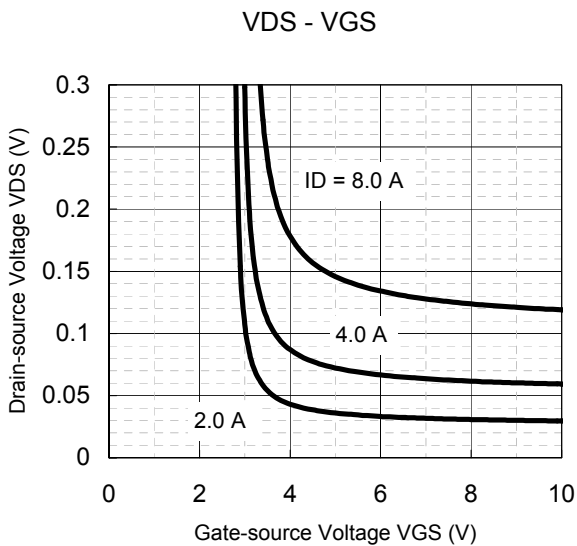
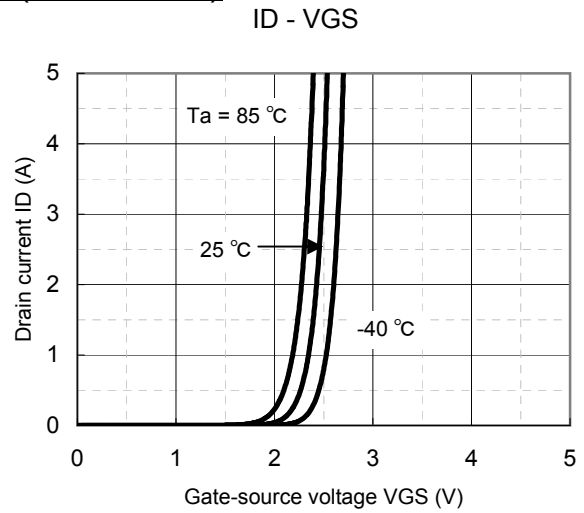
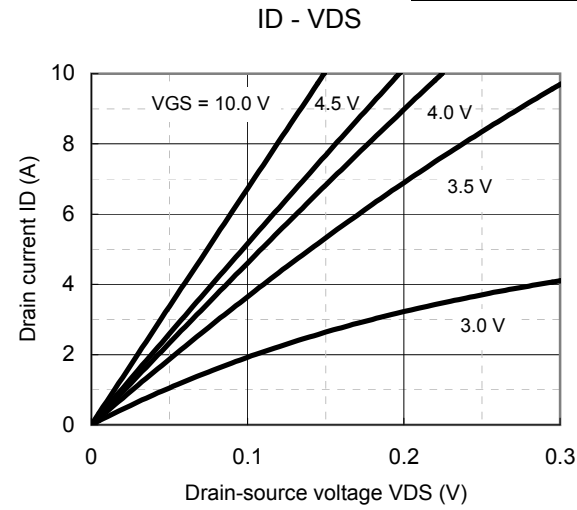
2. \*1 Pulse test: Ensure that the channel temperature does not exceed 150°C

\*2 Measurement circuit for Turn-on Delay Time/Rise Time/Turn-off Delay Time/Fall Time

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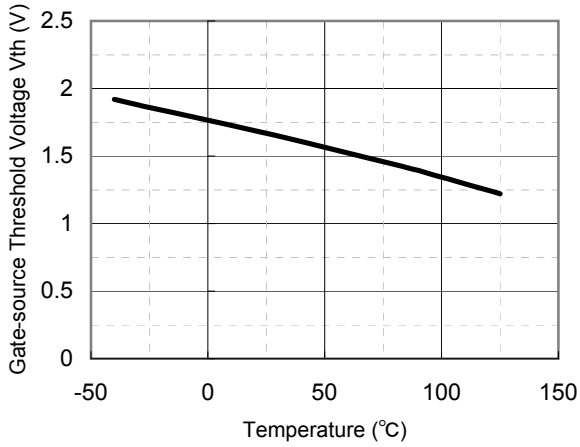


Technical Data ( reference )

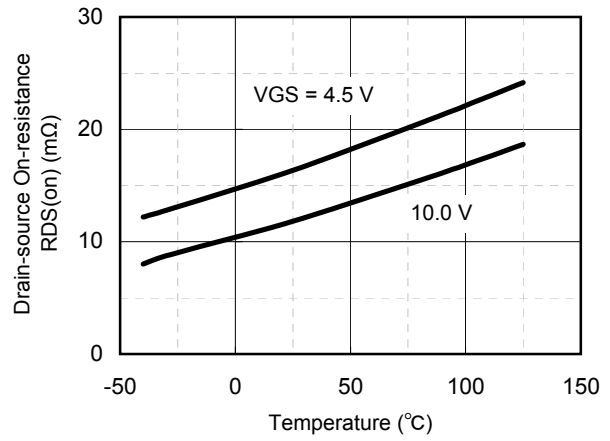


Technical Data ( reference )

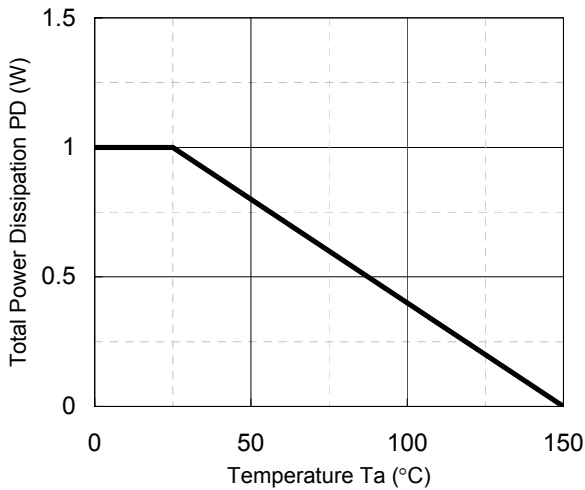
V<sub>th</sub> - T<sub>a</sub>



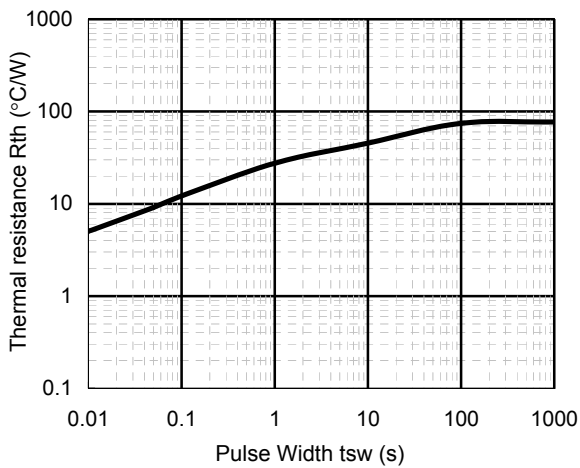
R<sub>DS(on)</sub> - T<sub>a</sub>



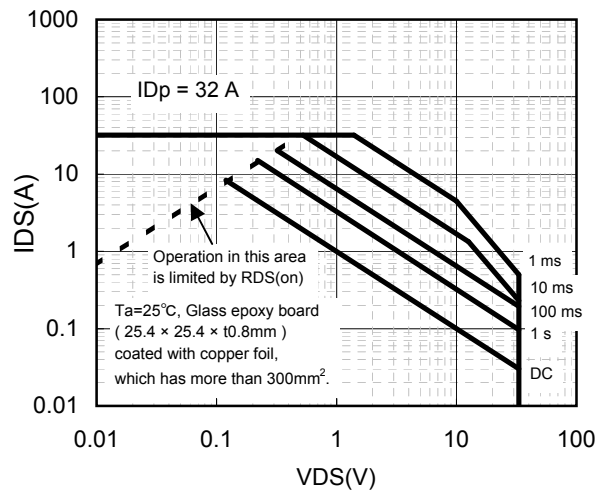
PD - T<sub>a</sub>



R<sub>th</sub> - t<sub>sw</sub>

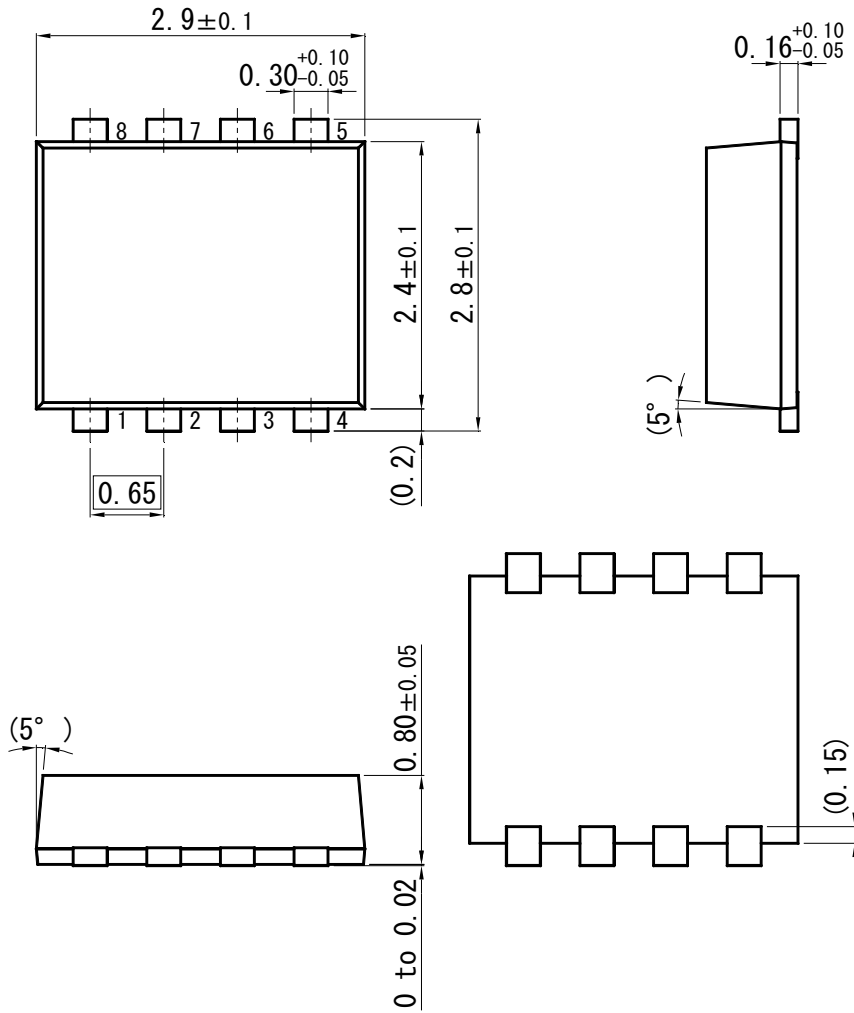


Safe Operating Area

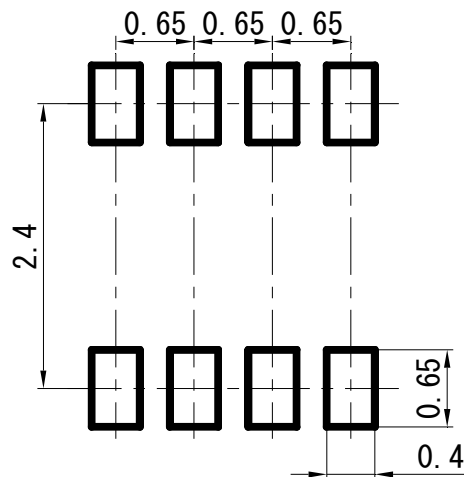


WMini8-F1

Unit : mm



■ Land Pattern (Reference) (Unit : mm)



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